SQ4470EY

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Vishay Siliconix

Automotive N-Channel 60 V (D-S) 175 °C MOSFET



| PRODUCT SUMMARY | | | | |
|---|--------|--|--|--|
| V _{DS} (V) | 60 | | | |
| $R_{DS(on)}(\Omega)$ at $V_{GS} = 10 V$ | 0.012 | | | |
| $R_{DS(on)}(\Omega)$ at $V_{GS} = 6 V$ | 0.014 | | | |
| I _D (A) | 16 | | | |
| Configuration | Single | | | |

FEATURES

- TrenchFET[®] power MOSFET
- AEC-Q101 qualified^c
- 100 % $R_{\rm q}$ and UIS tested
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

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ROHS COMPLIANT HALOGEN FREE

| Configuration | Single | N-Channel MOSFET | | |
|---------------------------------|--------|---|--|--|
| ORDERING INFORMA | ΓΙΟΝ | | | |
| Package | | SO-8 | | |
| Lead (Pb)-free and halogen-free | 9 | SQ4470EY (for detailed order number please see www.vishav.com/doc?7977 | | |

| ABSOLUTE MAXIMUM RATINGS ($T_c = 25 \degree C$, unless otherwise noted) | | | | | |
|--|-------------------------|-----------------------------------|--------------|------|--|
| PARAMETER | | SYMBOL | LIMIT | UNIT | |
| Drain-source voltage | | V _{DS} | 60 | v | |
| Gate-source voltage | | V _{GS} | ± 20 | | |
| Continuous drain current | T _C = 25 °C | | 16 | | |
| | T _C = 125 °C | I _D | 9 | | |
| Continuous source current (diode conduction) | | ۱ _S | 6 | A | |
| Pulsed drain current ^a | | I _{DM} | 67 | | |
| Single pulse avalanche current | | I _{AS} | 50 | | |
| Single pulse avalanche energy | L = 0.1 mH | E _{AS} | 125 | mJ | |
| Maximum power dissipation ^a | T _C = 25 °C | P | 7.1 | - w | |
| | T _C = 125 °C | P _D | 2.3 | | |
| Operating junction and storage temperature range | | T _J , T _{stg} | -55 to + 175 | °C | |

| THERMAL RESISTANCE RATINGS | | | | | |
|----------------------------|------------------------|-------------------|-------|------|--|
| PARAMETER | | SYMBOL | LIMIT | UNIT | |
| Junction-to-ambient | PCB mount ^b | R _{thJA} | 80 | °C/W | |
| Junction-to-case (drain) | on-to-case (drain) | | 21 | C/W | |

Notes

a. Pulse test; pulse width $\leq 300~\mu s,~duty~cycle \leq 2~\%$

b. When mounted on 1" square PCB (FR-4 material)

c. Parametric verification ongoing

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| PARAMETER | SYMBOL | TEST CONDITIONS | | MIN. | TYP. | MAX. | UNIT |
|---|---------------------------|--|---|------|----------|----------|------|
| Static | | | | I | <u> </u> | <u> </u> | |
| Drain-source breakdown voltage | V _{DS} | $V_{GS} = 0, I_D = 250 \ \mu A$ | | 60 | - | - | v |
| Gate-source threshold voltage | V _{GS(th)} | V _{DS} = | $V_{DS} = V_{GS}, I_D = 250 \ \mu A$ | | 3.0 | 3.5 | |
| Gate-source leakage | I _{GSS} | $V_{DS} = 0 V, V_{GS} = \pm 20 V$ | | - | - | ± 100 | nA |
| | | $V_{GS} = 0 V$ | V _{DS} = 60 V | - | - | 1.0 | |
| Zero gate voltage drain current | I _{DSS} | $V_{GS} = 0 V$ | V _{DS} = 60 V, T _J = 125 °C | - | - | 50 | μA |
| | | $V_{GS} = 0 V$ | V _{DS} = 60 V, T _J = 175 °C | - | - | 250 | |
| On-state drain current ^a | I _{D(on)} | V _{GS} = 10 V | $V_{DS} \ge 5 V$ | 30 | - | - | Α |
| | | $V_{GS} = 10 V$ | I _D = 6 A | - | 0.010 | 0.012 | Ω |
| | | V _{GS} = 10 V | I _D = 6 A, T _J = 125 °C | - | - | 0.021 | |
| Drain-source on-state resistance ^a | R _{DS(on)} | V _{GS} = 10 V | I _D = 6 A, T _J = 175 °C | - | - | 0.025 | |
| | | $V_{GS} = 6 V$ | I _D = 5 A | - | 0.012 | 0.014 | |
| Forward transconductance b | g _{fs} | V _{DS} | = 15 V, I _D = 6 A | - | 25 | - | S |
| Dynamic ^b | • | · | | | | | |
| Input capacitance | C _{iss} | | | - | 2531 | 3165 | pF |
| Output capacitance | C _{oss} | $V_{GS} = 0 V$ | V _{DS} = 25 V, f = 1 MHz | - | 382 | 480 | |
| Reverse transfer capacitance | C _{rss} | 1 | | - | 153 | 195 | |
| Total gate charge ^c | Qg | | | - | 45 | 68 | |
| Gate-source charge ^c | Q _{gs} | V _{GS} = 10 V | $V_{DS} = 30 \text{ V}, I_{D} = 12 \text{ A}$ | - | 9.9 | - | nC |
| Gate-drain charge ^c | Q _{gd} | 1 | | - | 11.2 | - | |
| Gate resistance | R _g | f = 1 MHz | | 0.40 | 0.87 | 1.30 | Ω |
| Turn-on delay time ^c | t _{d(on)} | $\label{eq:V_DD} \begin{array}{l} V_{DD}=30 \text{ V}, \text{ R}_L=2.5 \ \Omega \\ \text{I}_D\cong 12 \text{ A}, \text{ V}_{GEN}=10 \text{ V}, \text{ R}_g=1 \ \Omega \end{array}$ | | - | 13 | 20 | |
| Rise time ^c | tr | | | - | 12 | 18 | |
| Turn-off delay time ^c | t _{d(off)} | | | - | 25 | 38 | ns |
| Fall time ^c | t _f | | | - | 9 | 14 | |
| Source-Drain Diode Ratings and Char | racteristics ^b | · | | | | | |
| Pulsed current ^a | I _{SM} | | | - | - | 67 | А |
| Forward voltage | V _{SD} | I _F = 1.7 A, V _{GS} = 0 | | - | 0.72 | 1.2 | V |

Notes

d. Pulse test; pulse width $\leq 300~\mu s,~duty~cycle \leq 2~\%$

e. Guaranteed by design, not subject to production testing

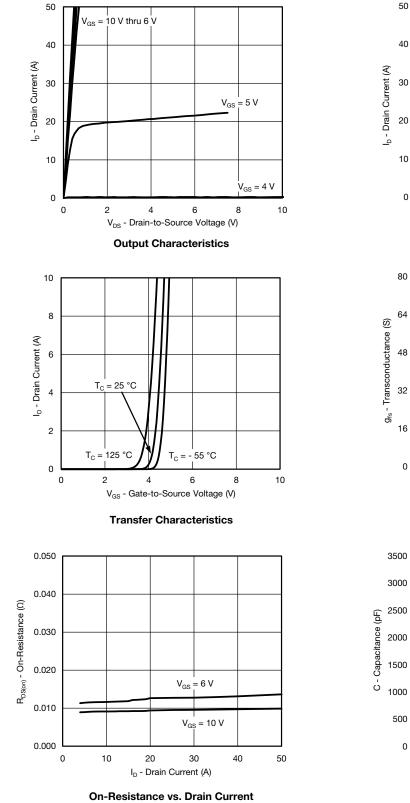
f. Independent of operating temperature

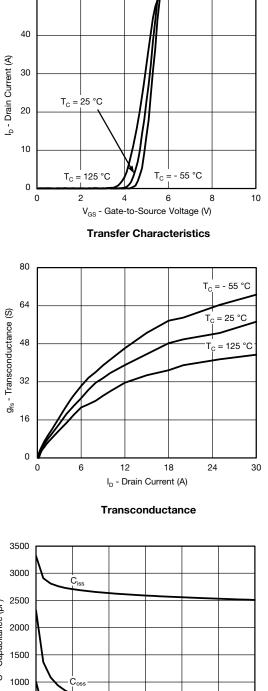
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

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TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)





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V_{DS} - Drain-to-Source Voltage (V)

20

25

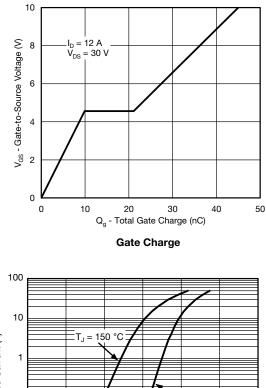
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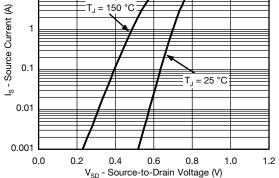
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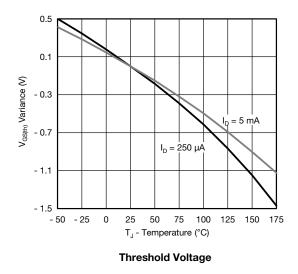


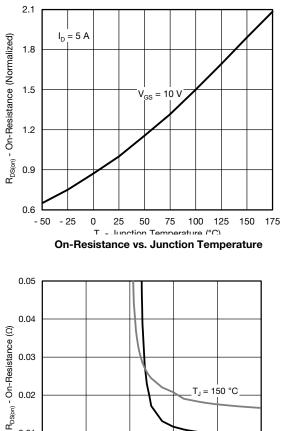
TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)

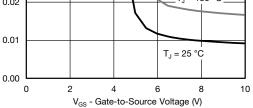




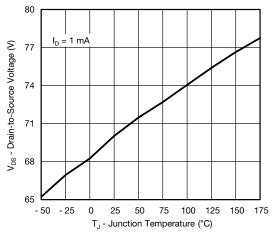
Source Drain Diode Forward Voltage







On-Resistance vs. Gate-to-Source Voltage



Drain Source Breakdown vs. Junction Temperature

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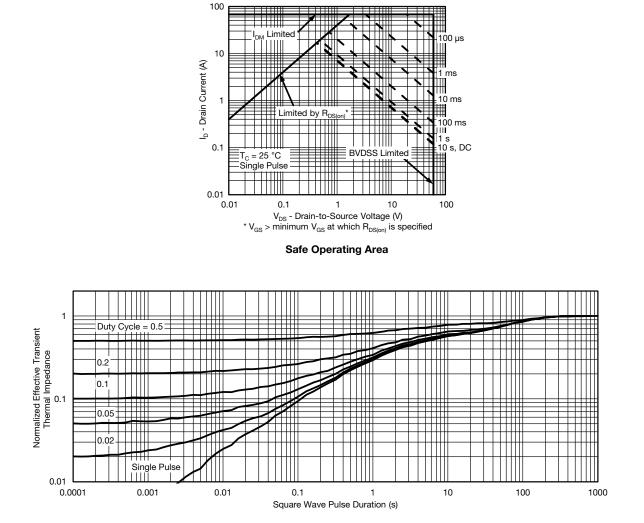
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THERMAL RATINGS ($T_A = 25 \text{ °C}$, unless otherwise noted)



Normalized Thermal Transient Impedance, Junction-to-Ambient

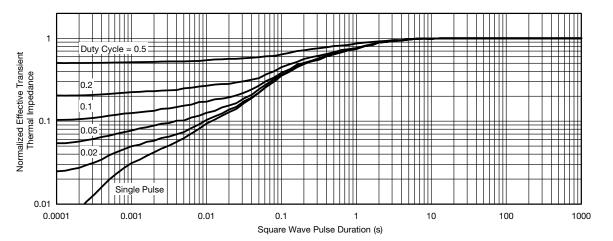


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THERMAL RATINGS (T_A = 25 °C, unless otherwise noted)



Normalized Thermal Transient Impedance, Junction-to-Foot

Note

The characteristics shown in the two graphs

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- Normalized Transient Thermal Impedance Junction-to-Ambient (25 °C)

- Normalized Transient Thermal Impedance Junction-to-Foot (25 °C)

are given for general guidelines only to enable the user to get a "ball park" indication of part capabilities. The data are extracted from single pulse transient thermal impedance characteristics which are developed from empirical measurements. The latter is valid for the part mounted on printed circuit board - FR4, size 1" x 1" x 0.062", double sided with 2 oz. copper, 100 % on both sides. The part capabilities can widely vary depending on actual application parameters and operating conditions

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see www.vishay.com/ppg?65673.



Package Information

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SOIC (NARROW): 8-LEAD JEDEC Part Number: MS-012

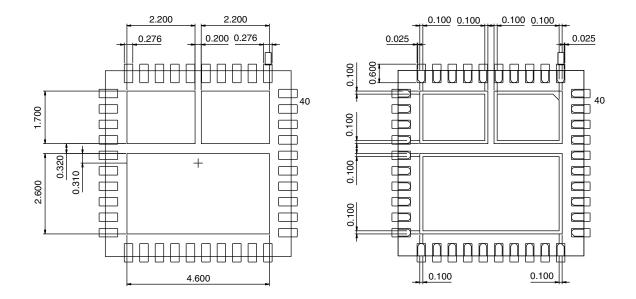




| | MILLIM | IETERS | INCHES | | |
|---|--------|--------|-----------|-------|--|
| DIM | Min | Мах | Min | Max | |
| A | 1.35 | 1.75 | 0.053 | 0.069 | |
| A ₁ | 0.10 | 0.20 | 0.004 | 0.008 | |
| В | 0.35 | 0.51 | 0.014 | 0.020 | |
| С | 0.19 | 0.25 | 0.0075 | 0.010 | |
| D | 4.80 | 5.00 | 0.189 | 0.196 | |
| E | 3.80 | 4.00 | 0.150 | 0.157 | |
| е | 1.27 | BSC | 0.050 BSC | | |
| н | 5.80 | 6.20 | 0.228 | 0.244 | |
| h | 0.25 | 0.50 | 0.010 | 0.020 | |
| L | 0.50 | 0.93 | 0.020 | 0.037 | |
| q | 0° | 8° | 0° | 8° | |
| S | 0.44 | 0.64 | 0.018 | 0.026 | |
| ECN: C-06527-Rev. I, 11-Sep-06 DWG: 5498 | | | | | |



Recommended Land Pattern PowerPAK® MLP66-40L



All Dimensions are in milimeters

Application Note 826

Vishay Siliconix



RECOMMENDED MINIMUM PADS FOR SO-8



Recommended Minimum Pads Dimensions in Inches/(mm)

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